, ",	Application No.	Applicant(s)	1000
Notice of Allowability	10/079,269	HOOPER ET AL.	
	Examiner	Art Unit	
	Robert M Kunemund	1765	
The MAILING DATE of this communication appeal All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate commu GHTS. This application is s	this application. If not included inication will be mailed in due cours	se. THIS
1. X This communication is responsive to applicants' response	of August 15, 2003.		
2. ⊠ The allowed claim(s) is/arę <u>1-3 and 5-19</u> .			
3. The drawings filed on 214 Dare accepted by the Examine	r.		
<ul> <li>4.  Acknowledgment is made of a claim for foreign priority ur</li> <li>a)  All b)  Some* c)  None of the:</li> <li>1.  Certified copies of the priority documents have</li> <li>2.  Certified copies of the priority documents have</li> <li>3.  Copies of the certified copies of the priority documents have</li> <li>International Bureau (PCT Rule 17.2(a)).</li> <li>* Certified copies not received:</li> </ul>	been received. been received in Applicatio	n No	rom the
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	of this communication to file ENT of this application.	a reply complying with the requirer	ments
5. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give	itted. Note the attached EXA es reason(s) why the oath or	MINER'S AMENDMENT or NOTIC declaration is deficient.	E OF
6. ☐ CORRECTED DRAWINGS ( as "replacement sheets") must (a) ☐ including changes required by the Notice of Draftspers 1) ☐ hereto or 2) ☐ to Paper No./Mail Date (b) ☐ including changes required by the attached Examiner's Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR 1, each sheet. Replacement sheet(s) should be labeled as such in the state of the property of t	on's Patent Drawing Review  Amendment / Comment or  84(c)) should be written on th	in the Office action of e drawings in the front (not the back	c) of
7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT	sit of BIOLOGICAL MATE	RIAL must be submitted. Note t	the
Attachment(s)  1. ☐ Notice of References Cited (PTO-892)  2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)  3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date  4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material	6. ☐ Interview Su Paper No./I 8), 7. ☒ Examiner's . —	ormal Patent Application (PTO-152 Immary (PTO-413), Mail Date Amendment/Comment Statement of Reasons for Allowand	,

Art Unit: 1765

## **EXAMINER'S AMENDMENT**

An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

The application has been amended as follows:

Cancel the abstract on page 36 of the specification and insert the following abstract found on the separate sheet of paper.

Application/Control Number: 10/079,269

Art Unit: 1765

## **ABSTRACT**

The invention provides a method of growing an (In, Ga) N multiplayer structure by molecular beam epitaxy. Each GaN or InGaN layer in the multiplayer structure is grown at a substrate temperature of at least 650°c, and this provides improved material quality. Ammonia gas is used as the source of nitrogen for the growth process.

Ammonia and gallium are supplied to the growth chamber at substantially constant rates, and the supply rate of indium to the growth chamber is varied to select the desired composition to be grown at a substantially constant growth rate. The substrate temperature is preferably kept constant during the growth process, to avoid the need to interrupt the growth process to vary the substrate temperature between the growth of one layer and the growth of another layer.

## **REASONS FOR ALLOWANCE**

The following is an examiner's statement of reasons for allowance: The prior art does not teach nor render obvious the instantly claimed subject matter. There is no teaching in the art to grow GaAIN layers by MBE where the indium rates are varied during growth. The prior art of record does teach growth of GaAIN layers with a varied concerntrations. However, the art does not teach the use of the MBE method where there is a variewd rate of indium. The prior art also teaches the use of purge or sweep gas between layers, the instant claims exclude this as the claims recite changing the indium rate during growth and not stopping the growth of the layers, which is done when using a purge gas. There is no teaching or suggestion in the art to grow the layers as is claimed.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Robert M Kunemund whose telephone number is 571-272-1464. The examiner can normally be reached on 8 hours.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571-272-1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Application/Control Number: 10/079,269

Art Unit: 1765

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

RMK

ROBERT KUNEMUND PRIMARY EXAMINER